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FCA35N60 N 沟道 SuperFET[®] MOSFET 600 V, 35 A, 98 mΩ

特性

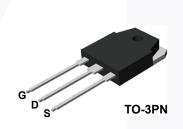
- 650V @ T_J = 150°C
- 典型值 R_{DS(on)} = 79 mΩ
- 超低栅极电荷(典型值 Q_g = 139 nC)
- 低有效输出电容 (典型值 C_{oss(eff.)}= 340 pF)
- 100% 经过雪崩测试

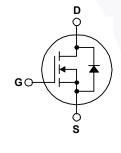
应用

- 太阳能逆变器
- AC-DC 电源



SuperFET[®]MOSFET 是飞兆半导体第一代利用电荷平衡技术实现出色低导通电阻和更低栅极电荷性能的高压超级结 (SJ) MOSFET 系列产品。这项技术专用于最小化导通损耗并提供卓越的开关性能、dv/dt 额定值和更高雪崩能量。因此,SuperFET MOSFET 非常适合开关电源应用,如功率因数校正 (PFC)、服务器/电信电源、平板电视电源、ATX 电源及工业电源应用。





MOSFET 最大额定值指的是 T_C=25℃ 除非另有说明。

符号	参数			FCA35N60	单位	
V _{DSS}	漏极一源极电压		600	V		
V _{GSS}	栅极至源极电压			±30	V	
		- 连续 (T _C = 25°C)		35	Α	
I _D	漏极电流	- 连续 (T _C = 100°C)		22.2		
I _{DM}	漏极电流	- 脉冲	105	Α		
E _{AS}	单脉冲雪崩能量 (注 2)		1455	mJ		
I _{AR}	雪崩电流 (注1)		35	А		
E _{AR}	重复雪崩能量 (注1)		31.25	mJ		
dv/dt	二极管恢复 dv/dt 峰值		(注3)	20	V/ns	
P _D	-1 +	(T _C = 25°C)		312.5	W	
	功耗	- 超过 25°C 时降额		2.5	W/°C	
T _J , T _{STG}	工作和存储温度范围			-55 至 +150	°C	
TL	用于焊接的最大引脚温度	,距离外壳 1/8",持续 5 秒		300	°C	

热性能

符号	参数	FCA35N60	单位
$R_{ ext{ heta}JC}$	结至外壳热阻最大值	0.4	°C/W
R_{\thetaJA}	结至环境热阻最大值	42	C/W

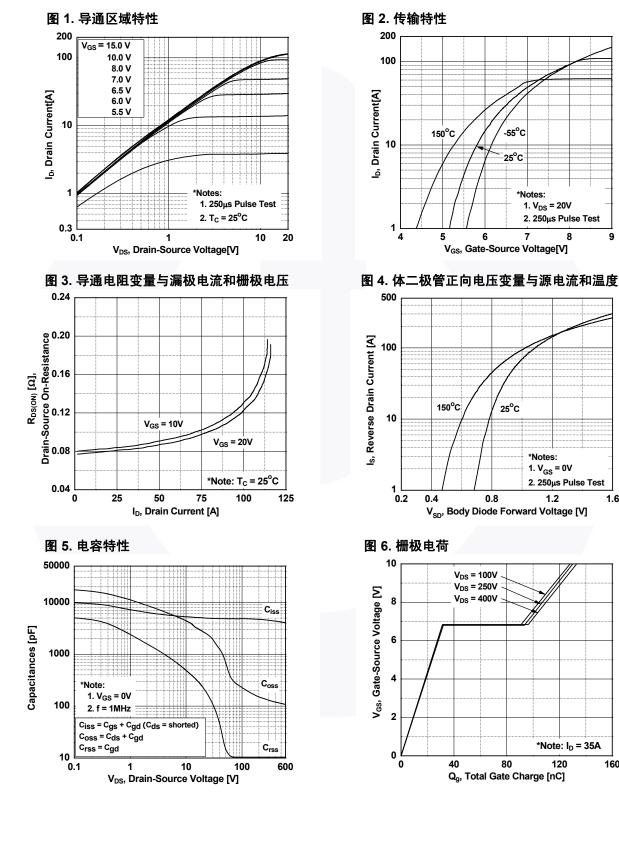
ਸ਼ਿੰਗ (T ਕ	器件编号 顶标		封装	包装方法	卷尺寸		带宽	数	量
		TO-3PN	塑料管	不适用	7	「适用	30 单元		
电气特性	E T _C = 25°C	除非另有说明。							
符号		参数		测试条件	ŧ	最小值	典型值	最大值	单位
关断特性									
BV _{DSS}	24. 浙	极击穿电压		$\frac{I_D = 250 \ \mu\text{A}, \ V_{GS} = 0 \ V, \ T_J = 25^{\circ}\text{C}}{I_D = 250 \ \mu\text{A}, \ V_{GS} = 0 \ V, \ T_J = 150^{\circ}\text{C}}$		600	-	-	V
	浦 似一	似				-	650	-	V
∆BV _{DSS} / ∆T _J	击穿电压	温度系数	1	_D = 250 μA,参考 25	°C	-	0.6	-	V/°C
B _{VDS}	漏源极雪	崩击穿电压	•	V _{GS} = 0 V, I _D = 16 A		-	700	-	V
VD3				$V_{\rm DS} = 600 \text{ V}, \text{ V}_{\rm GS} = 0$	V	-	-	1	
DSS	零栅极电	压漏极电流		$V_{\rm DS} = 480 \text{ V}, \text{ T}_{\rm C} = 125^{\circ}\text{C}$		-	-	10	μA
I _{GSS}	栅极 - 体流	屚电流		$V_{\rm GS} = \pm 30 \text{ V}, \text{ V}_{\rm DS} = 0$		-	-	±100	nA
导通特性									
V _{GS(th)}	栅极阈值	由压	,	V _{GS} = V _{DS} , I _D = 250 µ	A	3.0	-	5.0	V
R _{DS(on)}		极静态导通电阻		V _{GS} = 10 V, I _D = 17.5		-	0.079	0.098	Ω
9FS	正向跨导			V _{DS} = 40 V, I _D = 17.5		-	28.8	-	S
动态特性	L.								
	输入电容					_	4990	6640	pF
C _{oss}	<u> </u>		$V_{DS} = 25 \text{ V}, \text{ V}_{GS} = 0 \text{ V},$		_	2380	3170	pF	
C _{rss}	反向传输	由宓		f = 1 MHz		-	140	-	pF
C _{oss}	输出电容			V _{DS} = 480 V, V _{GS} = 0 V, f = 1 MHz		-	113	-	pF
C _{oss(eff.)}	有效输出电容			$V_{\rm DS} = 0 \text{ V to } 480 \text{ V}, V_{\rm GS} = 0 \text{ V}$		-	340	-	pF
Q _g	10 V 的栅极电荷总量			$V_{\rm DS} = 480 \text{ V}, \text{ I}_{\rm D} = 35 \text{ A},$		-	139	181	nC
Q _{gs}		极栅极电荷		V _{DS} = 480 V, 1 _D = 35 V _{GS} = 10 V	Α,	-	31	-	nC
Q _{gd}		汲 " 密勒 " 电荷		(说明 4)		-	69	-	nC
ESR	等效串联电阻 (G-S)			f = 1 MHz		-	1.4	-	Ω
开关特性									
t _{d(on)}	导通延迟	时间					34	78	ns
t _r	开通上升		,	V _{DD} = 300 V, I _D = 35 A, V _{GS} = 10 V, R _G = 4.7 Ω (说明 4)		-	120	250	ns
t _{d(off)}	关断延迟		,			6 -	105	220	ns
t _f	关断下降					-	73	155	ns
尾极 - 酒丸	及二极管特	性							
nni 12X - 145 12 S		I工 极二极管最大正向连续	申流			-	-	35	Α
I _{SM}	漏极 - 源极二极管最大正向陡冲电流					-	-	105	A
V _{SD}	漏极 - 源极二极管取入正问称冲电流 漏极 - 源极二极管正向电压			V _{GS} = 0 V, I _{SD} = 35 A		-	-	1.4	V
30	反向恢复			$V_{GS} = 0 V, I_{SD} = 35 A$ $V_{GS} = 0 V, I_{SD} = 35 A,$		-	614		ns
t _{rr}			$V_{GS} = 0 V, I_{SD} = 35 A,$ $dI_{F}/dt = 100 A/\mu s$					1	

3: $I_{SD} \le 35 \text{ A}$, di/dt $\le 200 \text{ A}/\mu$ s, $V_{DD} \le BV_{DSS}$, 启动 $T_J = 25^{\circ}$ C。

4:本质上独立于工作温度的典型特性。

FCA35N60 — N 沟道 SuperFET[®] MOSFET

典型性能特征



*Note: I_D = 35A

120

-55°C

25°C

*Notes:

7

6

V_{GS}, Gate-Source Voltage[V]

25°C

0.8

V_{DS} = 100V V_{DS} = 250V

V_{DS} = 400V

40

80

Q_g, Total Gate Charge [nC]

*Notes:

1. V_{GS} = 0V

1.2

2. 250µs Pulse Test

1.6

5

1. V_{DS} = 20V

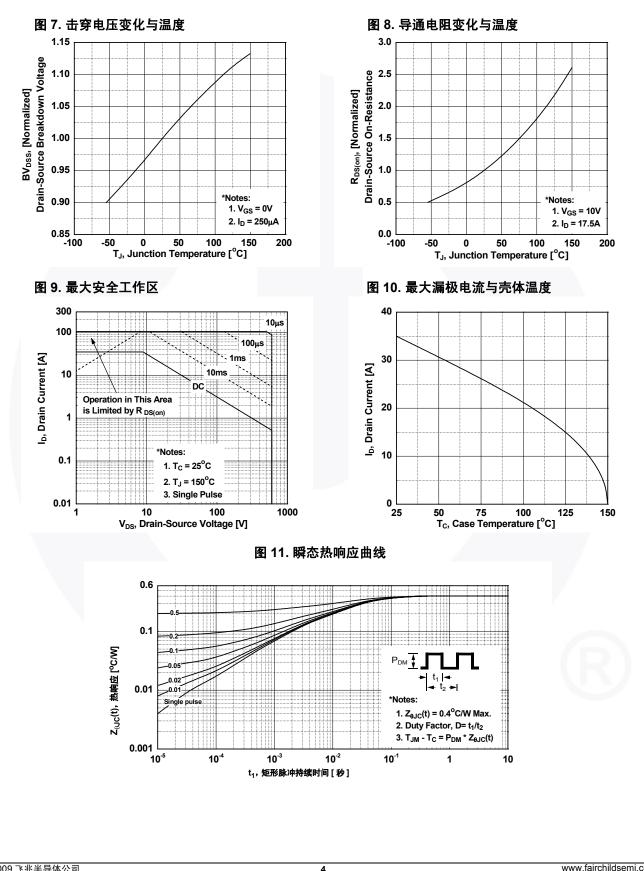
2. 250µs Pulse Test

8

9

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典型性能特征 (接上页)

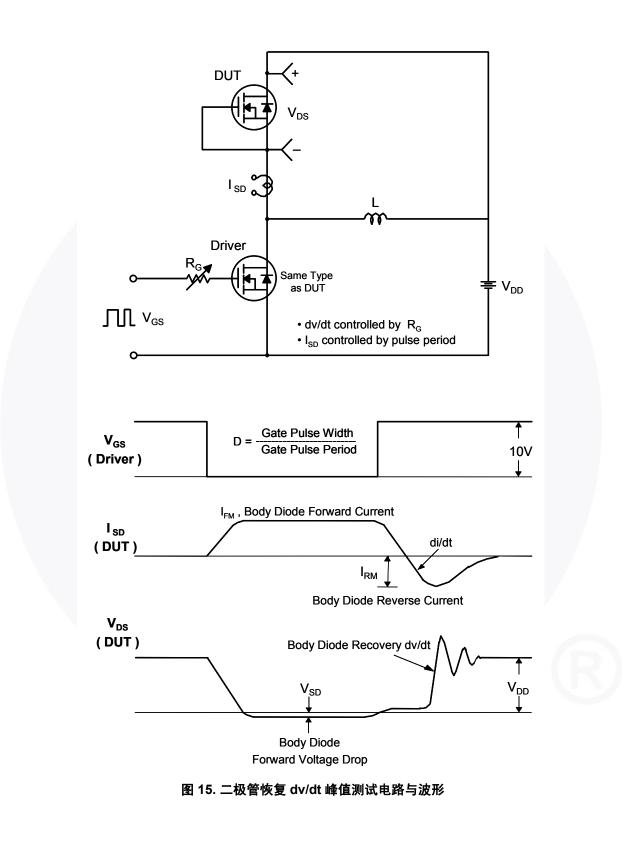


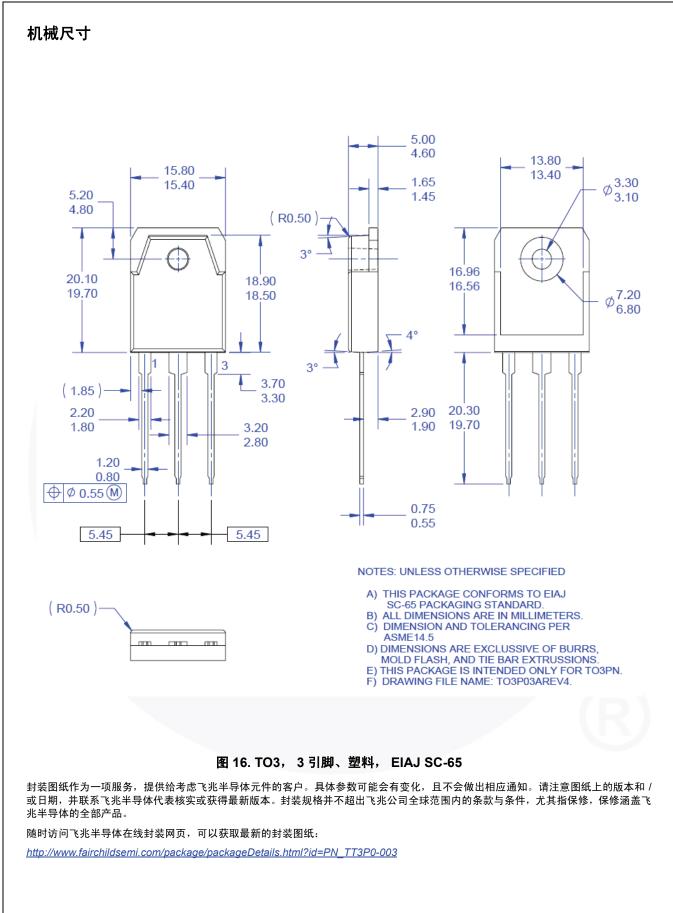
FCA35N60 — N 沟道 SuperFET[®] MOSFET

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 V_{GS} ⋛ᡔ Q_g FV_{DS} Q_{gd} Q_{gs} • DUT I_G = 常量 <u>*</u>∫ Charge 图 12. 栅极电荷测试电路与波形 R VDS V_{DS} 90% ο V_{DD} V_{GS} R_{G} 10% V_{GS} DUT V_{GS} ∏ a 图 13. 阻性开关测试电路与波形 L $E_{AS} = \frac{1}{2} L I_{AS}^2$ VDS $\mathsf{BV}_{\mathsf{DSS}}$ ۱_D م I_{AS} R_{G} ∔v₀ I_D (t) V_{GS} $V_{DS}(t)$ DUT V_{DD} Time t_p 图 14. 非箝位感性开关测试电路与波形

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